

1 310 nm FOR 1.25 Gb/s GIGABIT ETHERNET
InGaAsP MQW-FP LASER DIODE TOSA**DESCRIPTION**

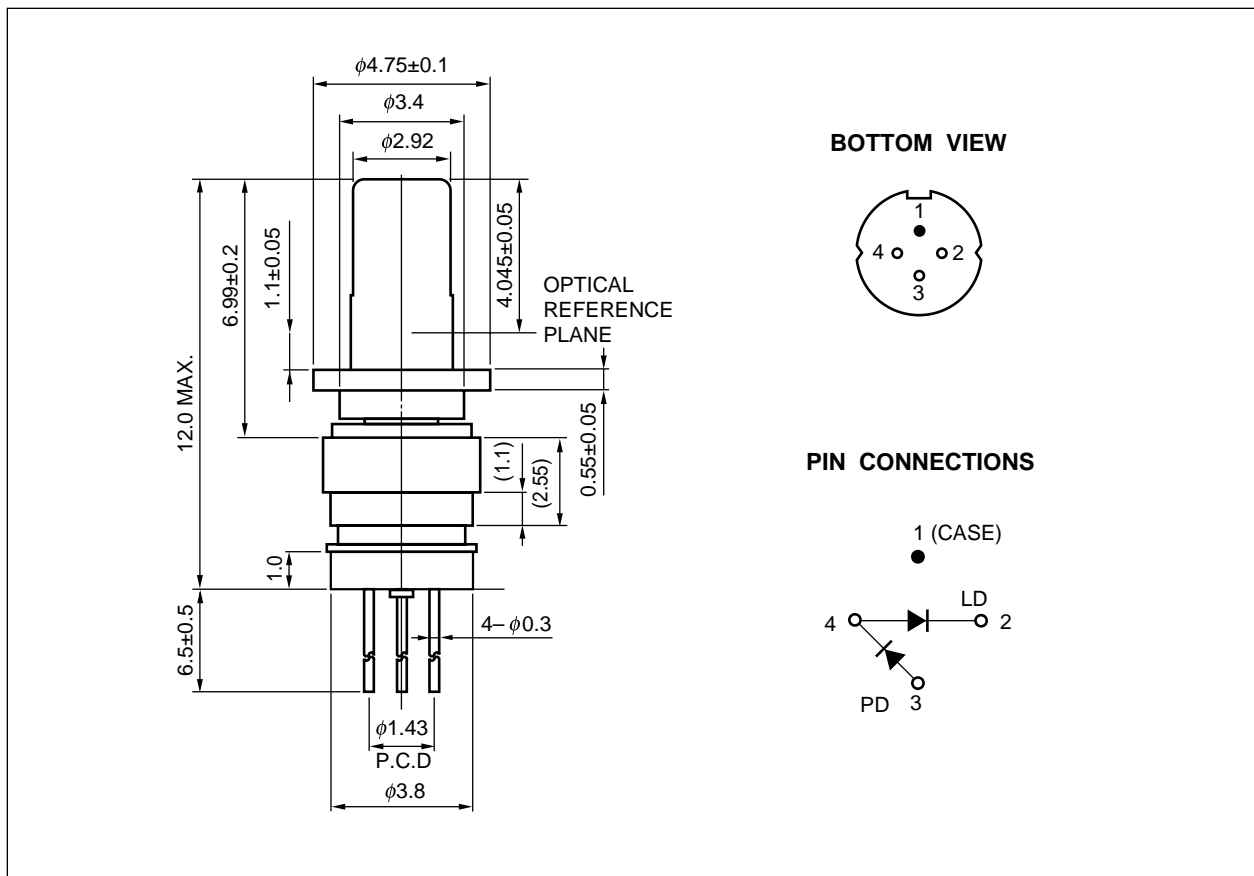
The NX7313UA is a 1 310 nm Multiple Quantum Well (MQW) structured Fabry-Perot (FP) laser diode TOSA (transmitter optical sub-assembly) with InGaAs monitor PIN-PD in a receptacle type package designed for SFF/SFP transceiver with LC duplex receptacle. This device is ideal for Gigabit Ethernet.

FEATURES

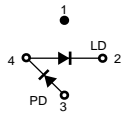
- For Gigabit Ethernet
- Optical output power $P_r = 0.6 \text{ mW}$
- Low threshold current $I_{th} = 8 \text{ mA TYP. @ } T_c = 25^\circ\text{C}$
- Wide operating temperature range $T_c = -40 \text{ to } +85^\circ\text{C}$
- InGaAs monitor PIN-PD
- Small package $\phi 3.8 \text{ mm TOSA (Total length 12.0 mm MAX.)}$
- Based on Telcordia reliability GR-468-CORE

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PACKAGE DIMENSIONS (UNIT: mm)



ORDERING INFORMATION

Part Number	Package	Pin Connections
NX7313UA	ϕ 3.8 mm TOSA	

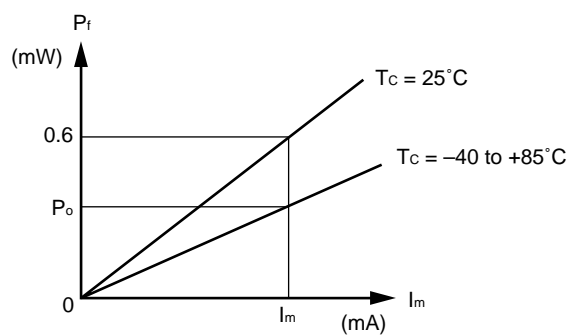
ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power from Fiber	P_f	2.0	mW
Forward Current of LD	I_F	150	mA
Reverse Voltage of LD	V_R	2.0	V
Forward Current of PD	I_F	10	mA
Reverse Voltage of PD	V_R	20	V
Operating Case Temperature	T_C	-40 to +85	°C
Storage Temperature	T_{stg}	-40 to +85	°C
Lead Soldering Temperature	T_{sld}	350 (3 sec.)	°C
Relative Humidity (noncondensing)	RH	85	%

ELECTRO-OPTICAL CHARACTERISTICS ($T_C = -40$ to $+85^{\circ}\text{C}$, unless otherwise specified)

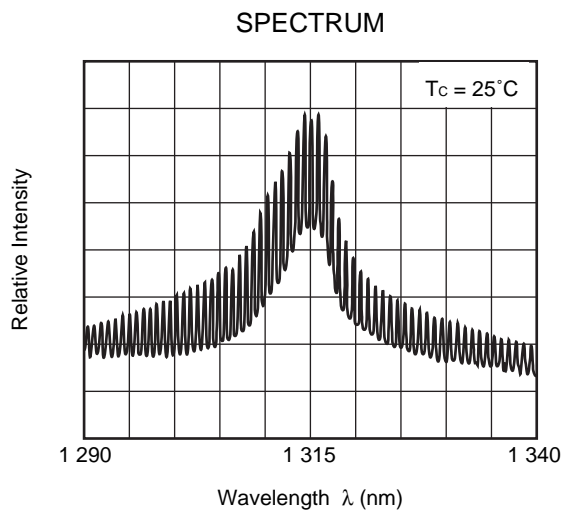
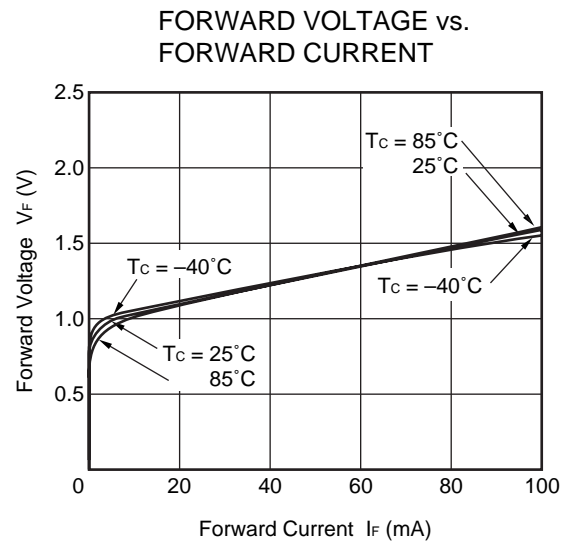
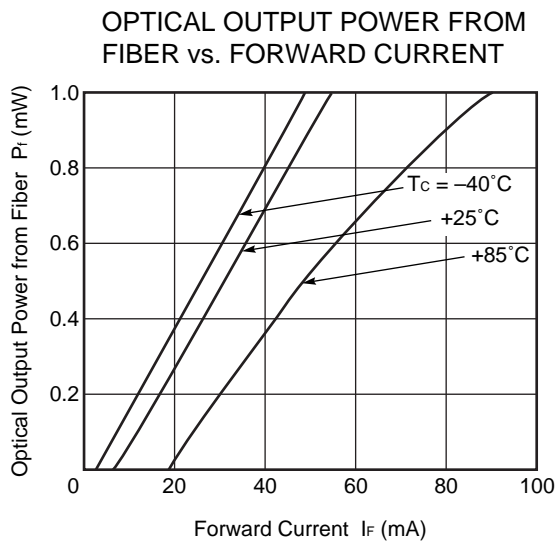
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating Voltage	V_{op}	CW, $P_f = 0.6$ mW	–	1.2	1.5	V
Threshold Current	I_{th}	CW	2	–	50	mA
		CW, $T_C = 25^{\circ}\text{C}$	4	8	20	
Optical Output Power from Fiber	P_f	CW	–	0.6	–	mW
Modulation Current	I_{mod}	CW, $P_f = 0.6$ mW	5	–	60	mA
		CW, $P_f = 0.6$ mW, $T_C = 25^{\circ}\text{C}$	8	25	45	
Differential Efficiency	η_d	CW	0.010	–	0.100	W/A
		CW, $T_C = 25^{\circ}\text{C}$	0.014	0.024	0.063	
Center Wavelength	λ_C	CW, $P_f = 0.6$ mW, RMS (–20 dB)	1 270	–	1 355	nm
Spectral Width	σ	CW, $P_f = 0.6$ mW, RMS (–20 dB)	–	–	4.0	nm
Rise Time	t_r	$I_b = I_{th}$, 10-90%	–	–	0.3	ns
Fall Time	t_f	$I_b = I_{th}$, 90-10%	–	–	0.3	ns
Monitor Current	I_m	CW, $V_R = 1.5$ V, $P_f = 0.3$ mW	200	–	1 200	μA
Monitor Dark Current	I_D	$V_R = 1.5$ V	–	–	500	nA
		$V_R = 1.5$ V, $T_C = 25^{\circ}\text{C}$	–	–	50	
Tracking Error ¹	γ	CW, $I_m = \text{const.}$ (@ $P_f = 0.6$ mW)	–1.5	–	1.5	dB
Connector Repeatability	–	With master pigtail	–1.0	–	1.0	dB

*1 Tracking Error: γ



$$\gamma = \left| 10 \log \frac{P_f}{0.6} \right| [\text{dB}]$$

TYPICAL CHARACTERISTICS ($T_c = 25^{\circ}\text{C}$, unless otherwise specified)



Remark The graphs indicate nominal characteristics.

LD ϕ 3.8 mm TOSA PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

Part Number	Absolute Maximum Ratings		Electro-Optical Characteristics				Application	Package
			@T _c = 25°C	@T _c				
	T _c (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)	λ (nm)			
			TYP.	TYP.	MIN.	MAX.		
NX7312UA	−40 to +85	−40 to +85	8	0.2	1 274	1 356	156 Mb/s: STM-1 (S-1.1)	ϕ 3.8 mm TOSA
							622 Mb/s: STM-4 (S-4.1)	
NX7313UA	−40 to +85	−40 to +85	8	0.6	1 270	1 355	1.25 Gb/s: GbE	ϕ 3.8 mm TOSA
NX7314UA	−40 to +85	−40 to +85	8	1.0	1 263	1 360	156 Mb/s: STM-1 (L-1.1)	ϕ 3.8 mm TOSA

REFERENCE

Document Name	Document No.
Optical semiconductor devices for fiberoptic communications Selection Guide	P12480E
Opto-Electronics Devices Pamphlet	P13623E
Opto-Electronics Devices (CD-ROM)	P12944X
NEC semiconductor device reliability/quality control system ^{*1}	C11159E
Quality grades on NEC semiconductor devices ^{*1}	C11531E
SEMICONDUCTOR SELECTION GUIDE –Products and Packages– ^{*1}	X13769E

^{*1} Published by NEC Corporation

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M8E 00.4-0110

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible
Laser Radiation is emitted from
this aperture

<div>Warning</div> <div>Laser Beam</div>	<p>A laser beam is emitted from this diode during operation. The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of eyesight.</p> <ul style="list-style-type: none"> • Do not look directly into the laser beam. • Avoid exposure to the laser beam, any reflected or collimated beam.
<div>Caution</div> <div>GaAs Products</div>	<p>The product contains gallium arsenide, GaAs. GaAs vapor and powder are hazardous to human health if inhaled or ingested.</p> <ul style="list-style-type: none"> • Do not destroy or burn the product. • Do not cut or cleave off any part of the product. • Do not crush or chemically dissolve the product. • Do not put the product in the mouth. <p>Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.</p>

► Business issue

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► Technical issue

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